

Multiscale Modelling with Accelerated Algorithms

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Multiscale Materials Modelling Simulation becomes increasingly important to understand phenomena at the nanoscale and develop novel materials. In recent years, we have developed multiscale simulation approaches for de-novo characterization and optimization of materials and device properties on the basis of their nanoscale constituents. Here we discuss development of the atomic molecular switches [1, 2], the electronic and structural properties of nanocarbon materials [3, 4, 5] and organic semiconductor devices [5, 6]. Small-molecule organic semiconductors are used in a wide spectrum of applications, ranging from organic light emitting diodes to organic photovoltaics. However, the low carrier mobility severely limits their potential, e.g. for large area devices. As an example of our methodology, we present a parameter-free model, which provides an accurate prediction of experimental data over ten orders of magnitude in mobility, and allows for the decomposition of the carrier mobility into molecule-specific quantities. We also demonstrate that a single molecular property, i.e. the dependence of the orbital energy on conformation, is the key factor defining mobility for hole transport materials. The availability of first-principles models to compute key performance characteristics of organic semiconductors may enable in-silico screening of numerous chemical compounds for the development of highly efficient opto-electronic devices.

References

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